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**SUPER BRIGHT ROUND TYPE LED LAMPS**



Lead-Free Parts

**L9UG3330-PF**

**DATA SHEET**

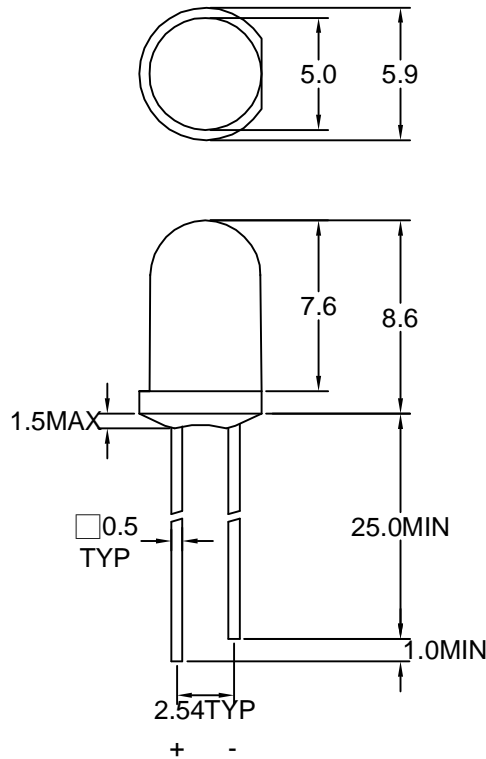
DOC. NO : QW0905-L9UG3330-PF

REV. : A

DATE : 02 - Aug. - 2006

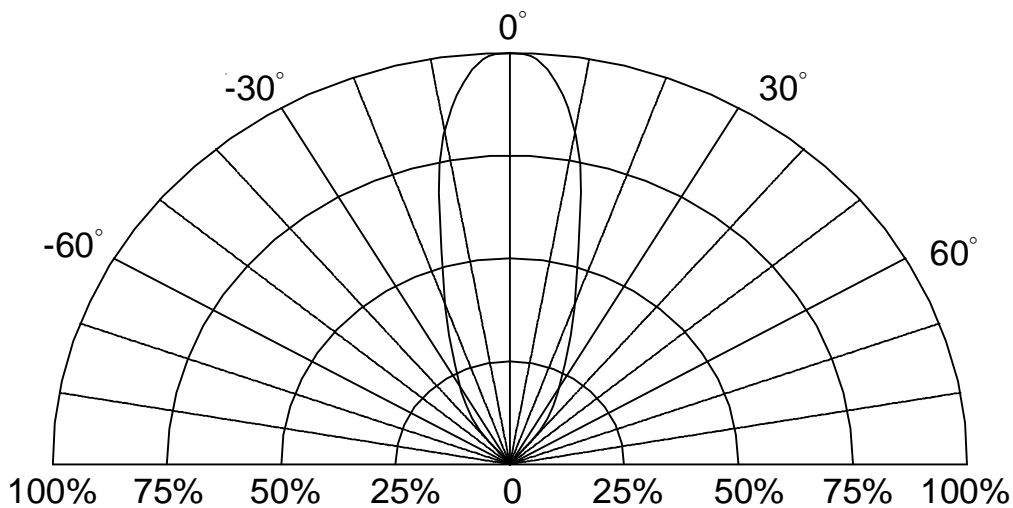


### Package Dimensions



Note : 1.All dimension are in millimeter tolerance is  $\pm 0.25$ mm unless otherwise noted.  
2.Specifications are subject to change without notice.

### Directivity Radiation



**Absolute Maximum Ratings at Ta=25 °C**

| Parameter                               | Symbol | Ratings    | UNIT |
|---|--------|------------|------|
|   |        | 9UG        |      |
| Forward Current                         | IF     | 30         | mA   |
| Peak Forward Current<br>Duty 1/10@10KHz | IFP    | 60         | mA   |
| Power Dissipation                       | PD     | 75         | mW   |
| Reverse Current @5V                     | Ir     | 10         | μA   |
| Electrostatic Discharge( * )            | ESD    | 2000       | V    |
| Operating Temperature                   | Topr   | -40 ~ +85  | °C   |
| Storage Temperature                     | Tstg   | -40 ~ +100 | °C   |

★ Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrostatic glove is recommended when handling these LED. All devices, equipment and machinery must be properly grounded.

**Typical Electrical & Optical Characteristics (Ta=25 °C)**

| PART NO     | MATERIAL | COLOR   |                | Dominant wave length<br>λ Dnm | Spectral halfwidth<br>Δ λ nm | Forward voltage<br>@20mA(V) |      | Luminous intensity<br>@20mA(mcd) |      | Viewing angle<br>2θ 1/2<br>(deg) |
|-------------|----------|---------|----------------|-------------------------------|------------------------------|-----------------------------|------|----------------------------------|------|----------------------------------|
|             |          | Emitted | Lens           |                               |                              | Min.                        | Max. | Min.                             | Typ. |                                  |
| L9UG3330-PF | AlGaInP  | Green   | Green Diffused | 574                           | 20                           | 1.7                         | 2.6  | 120                              | 220  | 36                               |

Note : 1.The forward voltage data did not including ±0.1V testing tolerance.  
2. The luminous intensity data did not including ±15% testing tolerance.



### Typical Electro-Optical Characteristics Curve 9UG CHIP

Fig.1 Forward current vs. Forward Voltage

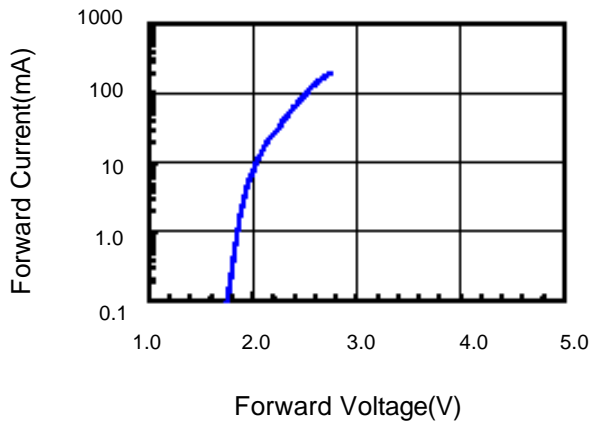


Fig.2 Relative Intensity vs. Forward Current

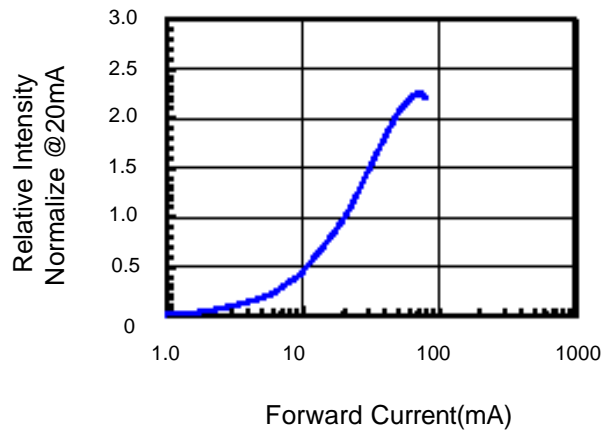


Fig.3 Forward Voltage vs. Temperature

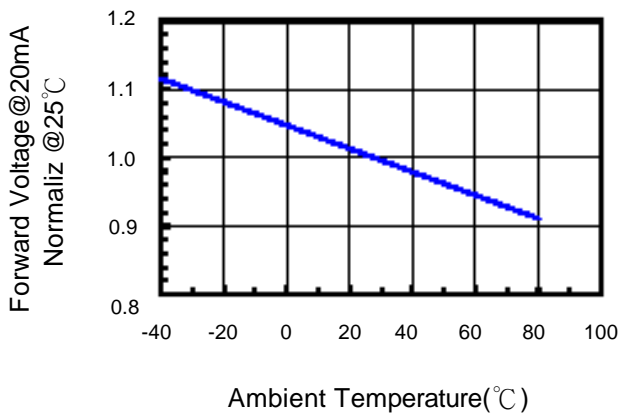


Fig.4 Relative Intensity vs. Temperature

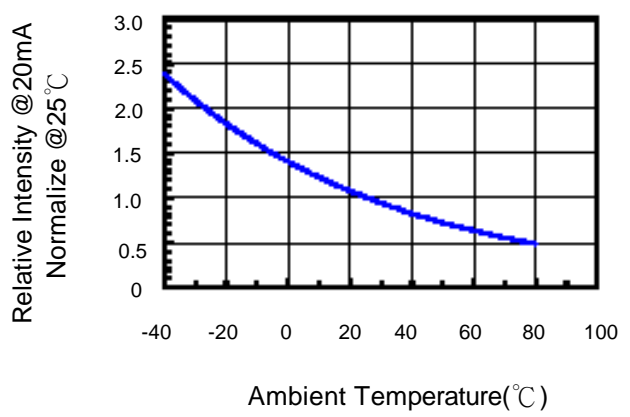
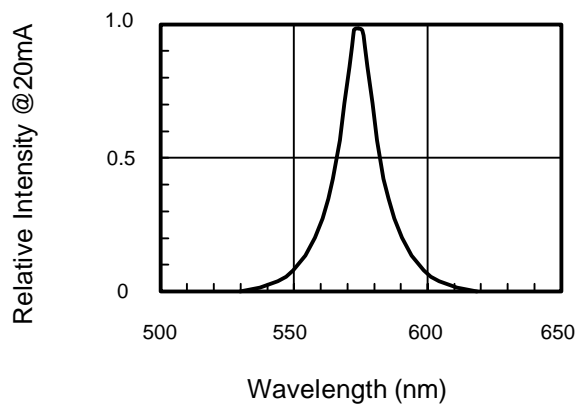


Fig.5 Relative Intensity vs. Wavelength





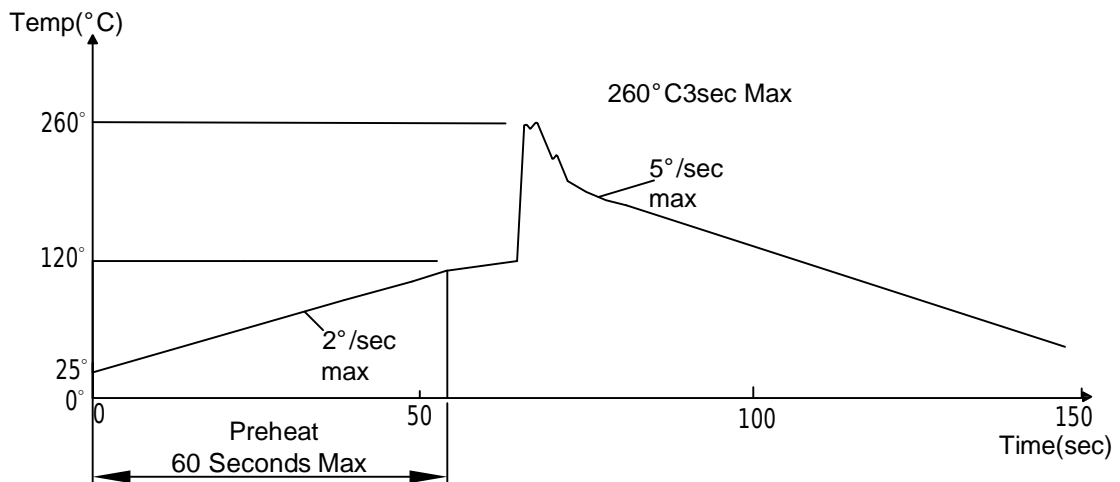
### Soldering Condition(Pb-Free)

#### 1.Iron:

- Soldering Iron:30W Max
- Temperature 350 ° C Max
- Soldering Time:3 Seconds Max(One Time)
- Distance:2mm Min(From solder joint to body)

#### 2.Wave Soldering Profile

- Dip Soldering
- Preheat: 120° C Max
- Preheat time: 60seconds Max
- Ramp-up
- 2° C/sec(max)
- Ramp-Down:-5° C/sec(max)
- Solder Bath:260° C Max
- Dipping Time:3 seconds Max
- Distance:2mm Min(From solder joint to body)





Reliability Test:

| Test Item                           | Test Condition   | Description   | Reference Standard   |
|-------------------------------------|--|---|--|
| Operating Life Test                 | 1.Under Room Temperature<br>2.If=20mA<br>3.t=1000 hrs (-24hrs, +72hrs) | This test is conducted for the purpose of determining the resistance of a part in electrical and thermal stressed.  | MIL-STD-750: 1026<br>MIL-STD-883: 1005<br>JIS C 7021: B-1                      |
| High Temperature Storage Test       | 1.Ta=105 °C ±5°C<br>2.t=1000 hrs (-24hrs, +72hrs)                      | The purpose of this is the resistance of the device which is laid under condition of high temperature for hours.  | MIL-STD-883:1008<br>JIS C 7021: B-10   |
| Low Temperature Storage Test        | 1.Ta=-40 °C ±5°C<br>2.t=1000 hrs (-24hrs, +72hrs)                      | The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.   | JIS C 7021: B-12   |
| High Temperature High Humidity Test | 1.Ta=65 °C ±5°C<br>2.RH=90 %-95%<br>3.t=240hrs ±2hrs                   | The purpose of this test is the resistance of the device under tropical for hours.  | MIL-STD-202:103B<br>JIS C 7021: B-11   |
| Thermal Shock Test                  | 1.Ta=105 °C ±5°C & -40 °C ±5°C<br>(10min) (10min)<br>2.total 10 cycles | The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature.  | MIL-STD-202: 107D<br>MIL-STD-750: 1051<br>MIL-STD-883: 1011                    |
| Solder Resistance Test              | 1.T.Sol=260 °C ±5°C<br>2.Dwell time= 10 ±1sec.                         | This test intended to determine the thermal characteristic resistance of the device to sudden exposures at extreme changes in temperature when soldering the lead wire. | MIL-STD-202: 210A<br>MIL-STD-750: 2031<br>JIS C 7021: A-1                      |
| Solderability Test                  | 1.T.Sol=230 °C ±5°C<br>2.Dwell time=5 ±1sec                            | This test intended to see soldering well performed or not.  | MIL-STD-202: 208D<br>MIL-STD-750: 2026<br>MIL-STD-883: 2003<br>JIS C 7021: A-2 |